TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K03TE

High Speed Switching Applications
Analog Switch Applications

- 2.5 V gate drive
- High input impedance
- Low gate threshold voltage: $V_{th} = 0.7 \sim 1.3 \text{ V}$
- Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	20	$\langle A \rangle$
Gate-source voltage	V_{GSS}	10	×
DC drain current	ΙD	100	> mA
Drain power dissipation	P_{D}	100	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	/°e

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings

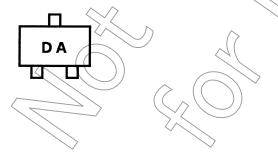
Unit: mm

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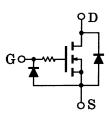
Weight: 0.0022g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Marking



Equivalent Circuit

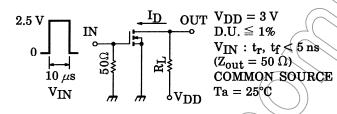


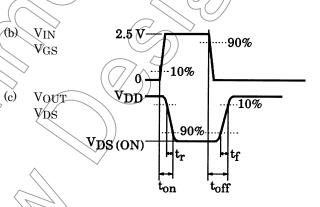
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	V _{GS} = 10 V, V _{DS} = 0	_	_	1	μА
Drain-source breakdown voltage		V (BR) DSS	$I_D = 100 \ \mu A, \ V_{GS} = 0$	20	_	_	V
Drain cut-off curre	nt	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0	\	_	1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.7	_	1.3	V
Forward transfer a	dmittance	Y _{fs}	V _{DS} = 3 V, I _D = 10 mA	25	50	_	mS
Drain-source ON r	esistance	R _{DS} (ON)	$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	<u> </u>	4	12	Ω
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz))	11.0	_	pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	_	3.3	_	pF
Output capacitance		Coss	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz	· —	9.3	_	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0 \sim 2.5 \text{ V}$	_	0.16	_	μ\$
	Turn-off time	t _{off}	$V_{DD} = 3 \text{ V}, I_D = 10 \text{ mA}, V_{GS} = 0~2.5 \text{ V}$		0.19	\rightarrow	

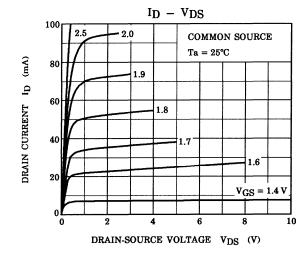
Switching Time Test Circuit

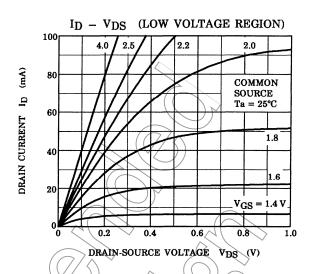
(a) Test circuit

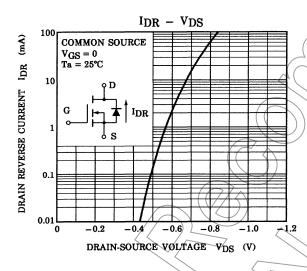


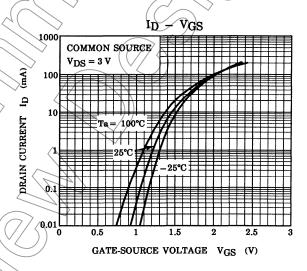


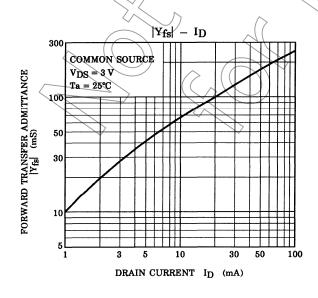
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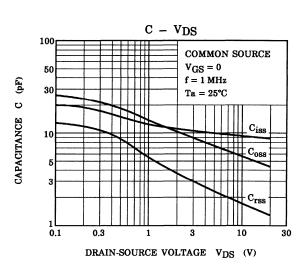




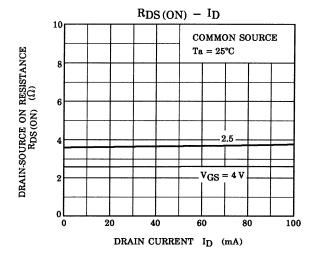


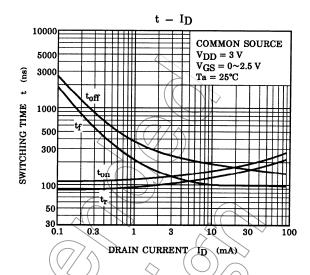


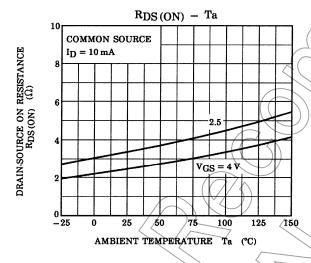


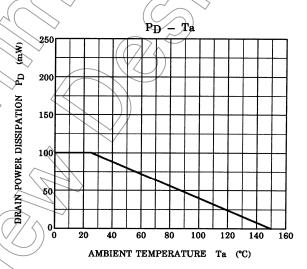


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